Switch-Mode Single Cell Li-Ion Charger with USB-OTG

General Description

The RT9460 is a switch-mode single cell Li-Ion/Li-Polymer battery charger for portable applications. It integrates a synchronous PWM controller, power MOSFETs, input current sensing and regulation, and high accuracy voltage regulation and charge termination circuits. Besides, the charging current is regulated through the integrated sensing resistors. The RT9460 also features USB On-The-Go (OTG) support.

The RT9460 optimizes the charging task by using a control algorithm to vary the charge rate via different modes, including pre-charge mode, fast charge mode, and constant voltage mode. The key charge parameters are programmable via the I²C interface. The RT9460 resumes the charge cycle whenever the battery voltage falls below an internal recharge threshold, and automatically enters sleep mode when the input power supply is removed.

Other features include under-voltage protection, overvoltage protection, thermal regulation and reverse leakage protection.

The RT9460 is available in the small WL-CSP-25B 2.52x2.52 packages.

The recommended junction temperature range is -40° C to 125° C, and the ambient temperature range is -40° C to 85° C.

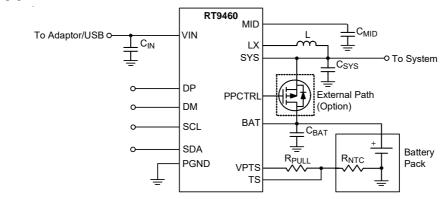
Features

- High Accuracy Voltage/Current Regulation
- Average Input Current Regulation (AICR) : 0.1/0.15/ 0.5/ to 3A per 0.1A
- Minimum Input Voltage Regulation
 For 5V Adaptor : 4V/4.25V/4.5V/4.75V
 For 9V Adaptor : 7V/7.5V/8V/8.5V
- Charge Current Regulation Accuracy : ±5%
- Charge Voltage Regulation Accuracy : ±1%
- Integrated Power MOSFETS for up to 3.125A Charge Rate
- Support USB Charging Detection
- Battery Temperature Sensing
- Synchronous 0.75/1.5MHz Fixed Frequency PWM Controller with Up to 95% Duty Cycle
- Reverse Leakage Protection to Prevent Battery Drainage
- Thermal Regulation and Protection
- Over Temperature Protection
- Input Over Voltage Protection
- IRQ Output for Communication with I²C
- Automatic Charging
- RoHS Compliant and Halogen Free

Applications

- Cellular Telephones
- Personal Information Appliances
- Tablet PC, Power Bank
- Portable Instruments

Simplified Application Circuit





Ordering Information

RT9460 🖵

Package Type WSC : WL-CSP-25B 2.52x2.52 (BSC)

Note :

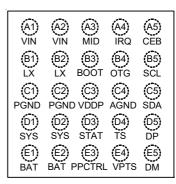
Richtek products are Richtek Green Policy compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.

Marking Information

0E YM DNN 0E : Product Code YMDNN : Date Code

Pin Configuration

(TOP VIEW)



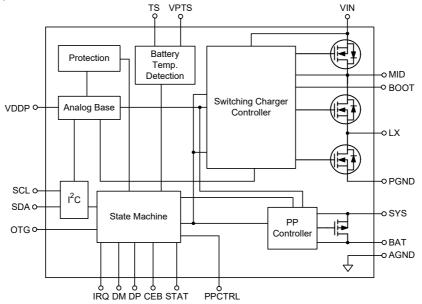
WL-CSP-25B 2.52x2.52 (BSC)

Functional Pin Description

Pin No.	Pin Name	Pin Description
A1, A2	VIN	Power input.
A3	MID	Connection point between reverse blocking MOSFET and high-side switching MOSFET.
A4	IRQ	IRQ output node.
A5	CEB	Enable control input. Low active. With internal 102k Ω pull low resistor.
B1, B2	LX	Switch node. Connect to an external inductor.
В3	воот	Bootstrap supply for high-side MOSFET. Connect a capacitor between BOOT and LX.
B4	OTG	Setting input pin OTG boost mode. With internal $102k\Omega$ pull low resistor.
B5	SCL	Clock input for I ² C. Open-drain output. Connect a pull-up resistor.
C1, C2	PGND	Power ground for switching charger.
C3	VDDP	Internal power for power stage.
C4	AGND	Analog ground.
C5	SDA	Data input for I ² C. Open drain output. Connect a pull-up Resistor.
D1, D2	SYS	System voltage regulator node.
D3	STAT	Charge status indicator (open drain).
D4	TS	Battery temperature detection pin.
D5	DP	USB charger type detection pin.
E1, E2	BAT	Charging current output node. Battery charging voltage regulation feedback pin with power path.
E3	PPCTRL	Power path control pin (connect to external P-MOSFET gate).
E4	VPTS	Supply voltage for battery temperature detection.
E5	DM	USB charger type detection pin.



Functional Block Diagram



Operation

The RT9460 is an integrated single cell Li-ion battery switching charger with power path controller.

Base Circuits

Base circuits provide the internal power, VDDP and reference voltage and bias current.

Protection Circuits

The protection circuits include the VINOVP, VINUVLO, BATOVP and OTP circuits. The protection circuits turn off the charging when the input power or die temperature is in abnormal level.

Buck Regulator for charging and Boost Regulator as OTG

The multi-loop controller controls the operation of charging process and current supply to the system. It also controls the circuits as a Boost converter for OTG applications.

Battery Detection

The RT9460 is capable of doing the battery absence detection. The detection protects the charger when battery is removed accidentally.

Adaptor Detection

If the poor input power source is connected to RT9460, the operation is shut down by the adaptor detection.

Power Path Management and Control

Once the battery voltage increase to a defined system minimum regulation voltage, the internal path between SYS and BAT will be fully turned on (Cool PPM operation). That is, a better charging efficiency can be derived. When end of charge occurs, the charing stops and the internal path will be off.

USB Charger Detection

The RT9460 detects and distinguishes SONY, APPLE NIKON and USB Charger (Standard Charger Port, Charging Downstream Port and Dedicated Charger Port) via DP and DM pins.

TS Detection

The RT9460 detects the temperature of the battery pack via TS and VPTS pins. The VPTS pin provides a constant voltage source used to drive the voltage divider composed of a pulled-high resister and a NTC resister. The RT9460 reports the sensing results via IRQ and status bits for COLD, COOL, WARM and HOT.

I²C Controller

The key parameters of charging and OTG are programmable through I^2C commands.

RT9460

Absolute Maximum Ratings (Note 1)

 Supply Input Voltage, VIN MID, BOOT LX 	0.3V to 28V
• MID – VIN, BOOT – LX	
Other Pins	0.3V to 6V
• Power Dissipation, $P_D @ T_A = 25^{\circ}C$	
WL-CSP-25B 2.52x2.52 (BSC)	3.11W
WQFN-32L 4x4	3.59W
Package Thermal Resistance (Note 2)	
WL-CSP-25B 2.52x2.52 (BSC), θ _{JA}	32.1°C/W
WQFN-32L 4x4, θ_{JA}	27.8°C/W
WQFN-32L 4x4, θ_{JC}	7°C/W
Lead Temperature (Soldering, 10 sec.)	260°C
Junction Temperature	150°C
Storage Temperature Range	–65°C to 150°C
ESD Susceptibility (Note 3)	
HBM (Human Body Model)	

Recommended Operating Conditions (Note 4)

Supply Input Voltage, VIN	- 4.3V to 9V
• Junction Temperature Range	40°C to 125°C
Ambient Temperature Range	 –40°C to 85°C

Electrical Characteristics

(VIN = 5V, VBAT = 4.2V, L = 2.2μ H, CIN = 2.2μ F, CBATS = 10μ F, TA = 25° C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Protection						
V _{IN} OVP Threshold Voltage			15	16	17	V
V _{IN} OVP Hysteresis				200		mV
Battery OVP			110	117	124	%
Battery OVP Hysteresis				10		%
Over-Temperature Protection	OTP			165		°C
OTP Hysteresis				10		°C
Thermal Regulation Threshold		Charge current begins to reduce		120		°C
System UVP Threshold Voltage	Vsys_uvp			2.4		V

Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit
Sleep Mode Comparator						
Sleep Mode Entry Threshold VIN – VBATS	VSLP	2.5V < VBATx < VBATREG, VIN falling	0	0.04	0.1	V
Sleep Mode Exit Hysteresis VIN – VBATS	VSLPEXIT	2.5V < VBATx < VBATREG	40	100	200	mV
Sleep Mode Deglitch Time				128		ms
Under-Voltage Lockout Thres	shold					
IC Active Threshold Voltage	Vuvlo	VIN rising	3.05	3.3	3.55	V
IC Active Hysteresis	ΔVυνίο	VIN falling from UVLO		150		mV
Input Currents		•		•		
		PWM switching, I _{CHG} = I _{BAT} = 0mA		10		mA
VIN Supply Current	IQ	PWM is not switching. I _{CHG} = I _{BAT} = 0mA			5	mA
		High impendence mode			150	μA
Leakage Current from Battery	IBAT	V _{IN} = 0V, charger off.			25	μA
Input Power Regulation		-				
Input Voltage Regulation	Vmivr	I ² C Programmable refer to Reg0x21[3:0]	4		8.5	V
VMIVR Accuracy			-5		5	%
		USB charge mode, I _{AICR} = 100mA	80		100	
Average Input Current Regulation Accuracy	IAICR	USB charge mode, IAICR = 500mA	SB charge mode, IAICR = 500mA 400 9			
r togalation / tooaraby		USB charge mode, IAICR = 1A	800		1000	
Battery Voltage Regulation						
Battery Voltage Regulation	Voreg	I ² C programmable per 20mV.	3.5		4.62	V
VBATREG Accuracy			-1		1	%
Re-Charge Threshold	VRECH	VBATx falling, below VBATREG		125		mV
Re-Charge Deglitch	TRECH			128		ms
System Minimum Regulation	Voltage					
System Minimum Regulation Voltage	Vsys	l ² C programmable per 0.1V	3.5		3.8	V
Charging Current Regulation						
Output Charging Current	Існд	I ² C programmable per 0.125A	1.25		3.125	А
ICHG Accuracy		AICR is disabled	-5		5	%
Pre-Charge Threshold	VPREC	I ² C programmable per 0.2V	2		3	V
VPREC Accuracy			-5		5	%
Pre-Charge Current	IPREC	I ² C programmable per 50mA	100		850	mA
IPREC Accuracy			-30		30	%

RT9460

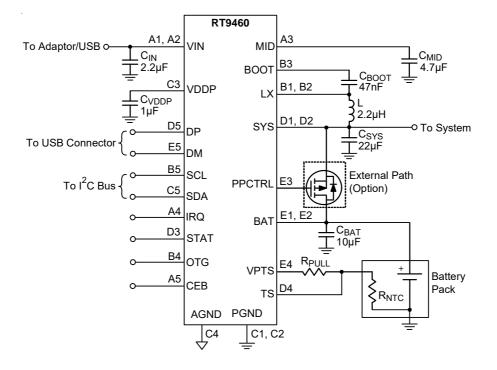
Parameter		Symbol	Test Conditions	Min	Тур	Max	Unit
Charge Terminati	on Detectio	n	•				
End of Charge Cur	rent	IEOC	I ² C programmable per 50mA	100		450	mA
Fixed IEOC			As I _{AICR} = 100mA		50		mA
IEOC Accuracy				-100		100	mA
Deglitch Time for E	OC	T _{EOC}	I _{CHG} < I _{EOC} , V _{BAT} > V _{REC}		2		ms
PWM							
High-Side On-Resi	istance		From VIN to LX, Exclude I _{AICR} = 100mA		90	150	mΩ
Low-Side On-Resis	stance		From LX to PGND		60	100	mΩ
Charging Efficiency	y		V_{BATx} = 4V, and I_{CHG} = 2A,		85		%
Oscillator Frequen	су	OSC	I ² C Programmable 0.75/1.5 MHz		1.5		MHz
Frequency Accura	су			-10		10	%
Maximum Duty Cy	cle		At minimum voltage input		95		%
Minimum Duty Cyc	le			0			%
Peak OCP as Charger Mode		Існдоср			4.5		А
Power Path On-Resistance			From SYS to VBAT		35	60	mΩ
Boost Mode Oper	ation					-	
Output Voltage Lev	/el	Votg	To VIN		5.05		V
Output Voltage Acc	curacy			-3		3	%
Efficiency			$V_{BATx} = 4V$, and $I_{IN} = 0.8A$,		85		%
MAX Output Curre	nt		I ² C programmable, 0.5A/1A	1			А
Peak Over-Current	t Protection				4.5		А
VIN OVP as OTG	Boost				6		V
VIN OVP Hysteres	is				250		mV
Minimum Battery \ Boost	ry Voltage for VBATMIN As boost start-up		As boost start-up		2.9		V
Minimum Battery Voltage Hysteresis					400		mV
I ² C Characteristic	s						
Output Low Voltage		Vol	I _{DS} = 10mA			0.4	V
SCL, SDA Input	Logic-High	Vih		1.3			V
Threshold Voltage	Logic-Low	VIL				0.4	V
SCL Clock						400	kHz

Parameter		Symbol	Test Conditions	Min	Тур	Max	Unit
DP DM Detection		•		•			
D+ Voltage Source		V _{DP_SCR}		0.5	0.6	0.7	V
D+ Voltage Source Current	Output			200			μA
D- Current Sink		Idm_sink		50	100	150	μA
Input Canaditanaa		C.	DM pin, switch open		4.5	5	ъ Г
Input Capacitance		Cı	DP pin, switch open		4.5	5	pF
Innutleakers		1.	DM pin, switch open	-1		1	A
Input leakage		1	DP pin, switch open	-1		1	μA
DP Low Comparate Threshold	or	V _{DP_LOW}		0.8			V
DM High Comparator Threshold		Vdm_high	M_HIGH				V
DM Low Comparator Threshold		Vdm_low				475	mV
NTC Monitor							
HOT Threshold	old Vvts_Hc		VTS falling, the ratio of VPTS, VIN > V _{IN(MIN)}	29	30	31	%VPTS
WARM Threshold	M Threshold Vvts_warm		VTS falling, the ratio of VPTS, VIN > V _{IN(MIN)}	37	38	39	%VPTS
COOL Threshold	L Threshold VVTS_COOL		VTS rising, the ratio of VPTS, VIN > V _{IN(MIN)}	55	56	57	%VPTS
COLD Threshold		Vvts_cold	VTS rising, the ratio of VPTS, VIN > V _{IN(MIN)}	59	60	61	%VPTS
Low Temperature Hysteresis		ΔV _{VTS}			1		%VPTS
Disable Threshold		Vvts_off	TS function disable	2	3	4	%VPTS
Control I/O Pin							
Output Low Voltage for STAT		Vol	I _{DS} = 10mA			0.4	V
CE Input	Logic-High	Vih		1.3			v
Threshold Voltage	Logic-Low	VIL				0.4	

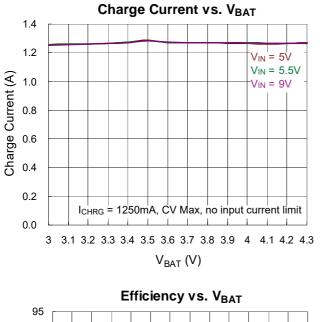
Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

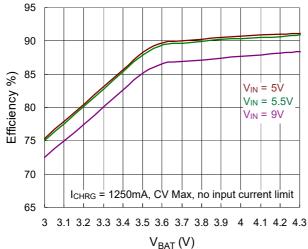
- Note 2. θ_{JA} is measured at $T_A = 25^{\circ}C$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7. θ_{JC} is measured at the exposed pad of the package.
- Note 3. Devices are ESD sensitive. Handling precautions are recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

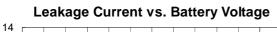
Typical Application Circuit

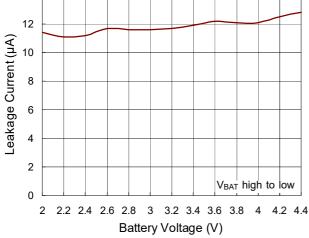


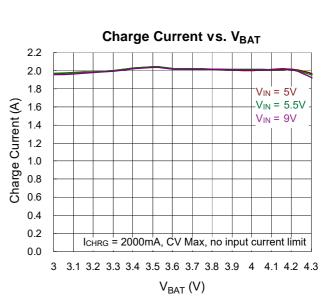


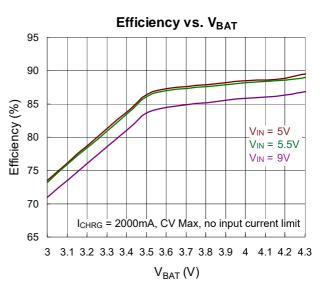




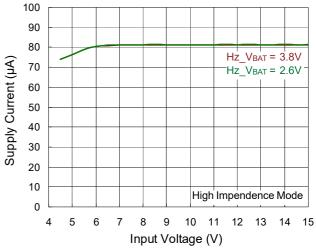




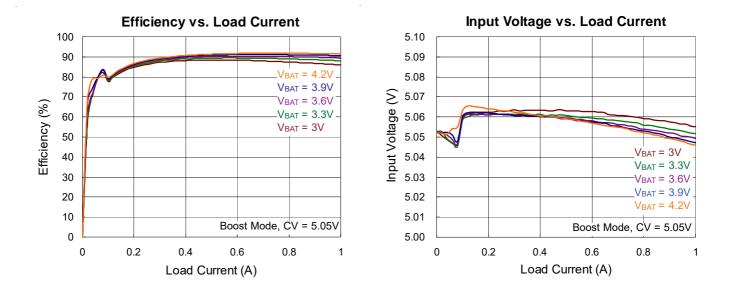




Supply Current vs. Input Voltage



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Application Information

Richtek's component specification does not include the following information in the Application Information section. Thereby no warranty is given regarding its validity and accuracy. Customers should take responsibility to verify their own designs and reserve suitable design margin to ensure the functional suitability of their components and systems.

The RT9460 switching charger integrates a synchronous PWM controller with power MOSFETs to provide input voltage MIVR (Minimum Input Voltage Regulation), input current AICR (Active Input Current Regulation), high accuracy current and voltage regulation, and charge termination. The charger also features USB OTG (On-The-Go).

The RT9460 has three operation modes : charge mode, boost mode (USB OTG), and high impedance mode. In charge mode, the RT9460 supports a precision charging system for single cell. In boost mode, the RT9460 works as the boost converter and boosts the voltage from battery to VIN pin for sourcing the OTG devices. In high impedance mode, the RT9460 stops charging or boosting and operates in a mode with low current from VIN or battery to reduce the power consumption when the portable device is in standby mode.

Notice that the RT9460 integrate input power source (AC adapter or USB input) detection. Thus, the RT9460 can automatically set the charge current by option. The charge current needs to be set via I²C interface by the host. The RT9460 application mechanism and I²C compatible interface are introduced in later sections.

Charge Mode Operation

Minimum Input Voltage Regulation (MIVR)

The RT9460 features input voltage MIVR function to prevent input voltage drop due to insufficient current provided by the adaptor or USB input. If MIVR function is enabled, the input voltage decreases when the over current of the input power source occurs. VIN is regulated at a predetermined voltage level which can be set as 4V to 8.5V by I²C interface. At this time, the current drawn by the RT9460 equals to the maximum current value that the input power can provide at the predetermined voltage level, instead of the set value.

Charge Profile

The RT9460 provides a precision Li-ion or Li-polymer charging solution for single-cell applications. Input current limit, charge current, termination current, charge voltage and input voltage MIVR are all programmable via the I²C interface. In charge mode, the RT9460 has five control loops to regulate input current (AICR), charge current, charge voltage, input voltage (MIVR) and device junction temperature. During the charging process, all five loops (if MIVR is enabled) are enabled and the dominant one will take over the control.

For normal charging process, the Li-ion or Li-polymer battery is charged in three charging modes depending on the battery voltage. At the beginning of the charging process, the RT9460 is in pre-charge mode. When the battery voltage rises above pre-charge threshold voltage (V_{PREC}), the RT9460 enters fast-charge mode. Once the battery voltage is close to the regulation voltage (V_{OREG}), the RT9460 enters constant voltage mode.

Pre-Charge Mode

For life-cycle consideration, the battery can not be charged with large current under low battery condition. When the BATS pin voltage is below pre-charge threshold voltage (V_{PREC}), the charger is in pre-charge mode with a weak charge current witch equals to the pre-charge current (I_{PREC}). There are two control loops in Pre-charge mode. One is the ICC and the other is the MIN_SYS. If the battery voltage is lower than the SYS voltage, the MOSFET won't fully turn-on to prevent the battery voltage to influence the SYS voltage. It features that the charger can also provide the current to the load from SYS even the battery voltage is too low. In pre-charge mode, the charger basically works as an LDO. The pre-charge current also acts as the current limit when the BATS pin is shorted. The Pre-Charge current levels are 100mA - 850mA programmed by I²C.

RT9460

Fast-Charge Mode and Settings

As the BAT pin rises above VPREC, the charger enters fast-charge mode and starts charging. Notice that the MUIC integrates input power source (AC adapter or USB input) detection. Thus, the switching charger can set the charge current by option automatically. Unlike the linear charger (LDO), the switching charger (Buck converter) is a current amplifier. The current drawn by the switching charger is different from the current into the battery.

The user can set the Average Input Current Regulation (AICR) and output charge current (I_{CHRG}) respectively.

Cycle-by-Cycle Current Limit

The charger of the RT9460 has an embedded cycle-bycycle current limit for inductor. Once the inductor current touches the threshold (4.5A typ.), the charger stops charging immediately to prevent over current from damaging the device. Notice that, the mechanism can not be disabled by any way.

Average Input Current Regulation (AICR)

The AICR setting is controlled by I^2C . The AICR100 mode limits the input current to 100mA. The AICR500 mode limits the input current to 500mA. If the application does not need input current limit, it can be disabled also. The AICR levels programmed by I^2C and suitable for USB port and several TA types.

Charge Current (I_{CHG})

The charge current into the battery is determined by the power path sensing RON and ICC setting by I^2C . The voltage between the SYS and BAT pins is regulated to the voltage control by ICC setting. ($I_{CC} \times R_{ON}, R_{ON}$: power path R_{ON})

At RT9460, the R_{ON} is $35 m \Omega$ and the Fast-Charge currents is set by the I^2C interface from 1.25A to 3.125A per 125mA.

Constant Voltage Mode and Settings

The RT9460 enters constant voltage mode when the BATS voltage is close to the output-charge voltage (V_{OREG}). In this mode, the charge current begins to decrease. For default settings (charge current termination is disabled),

the RT9460 does not turn off and always regulates the battery voltage at VOREG. However, once the charge current termination is enabled, the charger terminates if the charge current is below termination current (I_{EOC}) in constant-voltage mode. The charge current termination function is controlled by the I^2C interface.

After termination, a new charge cycle restarts when one of the following conditions is detected :

- The BATS pin voltage falls below the V_{OREG} V_{RECH} threshold.
- VIN Power On Reset (POR).
- CHG_EN bit toggle or RST bit is set (via I²C interface).

Output Charge Voltage (VOREG)

The output-charge voltage is set by the I^2C interface from 3.5V to 4.62V per 25mV. The default value is 4V (011001).

Termination Current (IEOC)

If the charger current termination is enabled (TE bit = "1" of REG0x01[3]), the end-of-charge current is determined by both termination current sense voltage (V_{EOC}) and power path sense resistor (R_{ON}). General R_{ON} is 35m Ω , IEOC is set by the I²C interface from 100mA to 450mA per 50mA.

Input Voltage Protection in Charge Mode

During charge mode, there are two protection mechanisms against if input power source capability is less than the charging current setting. One is AICR and the other is minimum input voltage regulation. A suitable level of AICR can prevent VBUS drop by the insufficient capability. As the AICR setting is not suitable, MIVR will regulate the VBUS in the setting level and sink the maximum current of power source.

Sleep Mode (V_{IN} - V_{BATS} < V_{SLP})

The RT9460 enters sleep mode if the voltage drop between the VIN and BATS pins falls below V_{SLP} . In sleep mode, the reverse blocking switch and PWM are all turned off. This function prevents battery drain during poor or no input power source.

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Input Over Voltage Protection

When VBUS rises above the input over voltage threshold, the switching charger stops charging and sets the fault status bits. The condition is released when VBUS falls below OVP threshold. The switching charger then resumes charging operation.

Boost Mode Operation (OTG) Trigger and Operation

The RT9460 features USB OTG support. When OTG function is enabled, the synchronous boost control loop takes over the power MOSFETs and reverses the power flow from the battery to the VIN pin. In normal boost mode, the VIN pin is regulated to the level controlled by VOREG[5:0] from 4.425V to 5.825 per 25mV. The boost provides up to 1A current to support other OTG devices connected to the USB connector.

Output Over Voltage Protection

In boost mode, the output over voltage protection is triggered when the VIN voltage is above the output OVP threshold. When OVP occurs, the boost converter stops switching and turns off immediately.

Output Overload Protection

The RT9460 provides an overload protection to prevent the device and battery from damage when VIN is overload. Once overload condition is detected, the reverse blocking switch operates in linear region to limit the output current while the MID voltage remains in voltage regulation. If the overload condition lasts for more than 32ms, the RT9460 will recognize the overload fault condition and resets registers to the default settings.

Battery Detection During Normal Charging

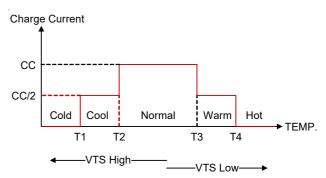
The RT9460 provides a battery absent detection scheme to detect insertion or removal of the battery pack. The battery detection scheme is valid only when both TE = 1 and BATD_EN = 1.

During normal charging process, once the charge done condition is satisfied ($V_{BATS} > V_{OREG} - V_{RECH}$ and termination current is detected), the RT9460 turns off the PWM converter and initiates a discharge current (detection current) for a detection time period. After that,

the RT9460 checks the BATS voltage. If it is still above the recharge threshold, the battery is present and charge done is detected. If the BATS voltage is below the recharge threshold, the battery is absent. Thus, the RT9460 stops charging and the charge parameters are reset to the default values. The charge resumes after a period of tDET (2sec. typ.).

JEITA Protection

To enhance thermal protection of battery, JEITA function is implemented in theRT9460. JEITA guideline was released in 2007. It includes Warm and cool protection (cool section is between T1 and T2; warm section is between T3 and T4, see the figure as below). When battery's temperature is in warm or cool section, the RT9460 will reduce charging current (by a half of CC mode current). The RT9460 stop charging if temperature is lower than T1 or is higher than T4.

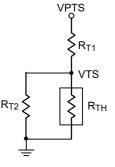


Thermal of battery can be monitored by TS PIN. There are 4 sections should be implemented in JEITA function. Base on R_{hot} and R_{cold} , RT1 and RT2 can be determined by equation (1) and equation (2).

(R_{hot} mean that system trigger battery OTP, R_{cold} mean that system trigger battery low temperature protection.)

$$R_{T1} = VPTS x [(1/V_{T1} - 1/V_{T4})/(1/R_{Cold} - 1/R_{Hot})]$$
(1)

$$R_{T2} = R_{T1} x [1 / (VPTS / V_{T1} - R_{T1} / R_{Cold} - 1)]$$
(2)



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RICHTEK

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

 $\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = (\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}) / \theta_{\mathsf{J}\mathsf{A}}$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For WL-CSP-25B 2.52x2.52 package, the thermal resistance, θ_{JA} , is 32.1°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at $T_A = 25$ °C can be calculated by the following formula :

 $P_{D(MAX)}$ = (125°C - 25°C) / (32.1°C/W) = 3.11W for WL-CSP-25B 2.52x2.52 package

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA} . The derating curve in Figure 1 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

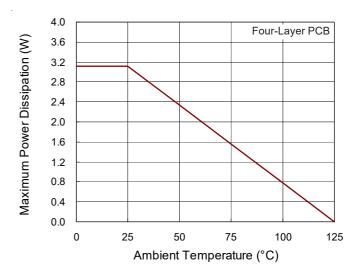


Figure 1. Derating Curve of Maximum Power Dissipation

Layout Considerations

- For AGND noise reduction, PGND and AGND should connect directly at top layer.
- For AGND noise reduction, PGND and AGND should be connected by ground plane at inner layer1. And this ground plane should be connected to system ground plane by via.
- VBUS and VMID (capacitor GND) should be connected to IC PGND directly at top layer.
- The output inductor and bootstrap capacitor should be placed close to the RT9460 and LX pins.

RT9460



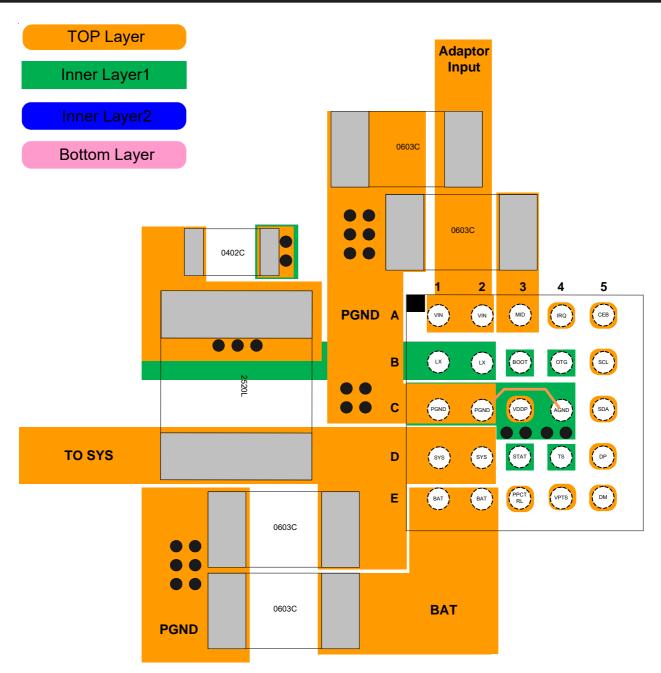


Figure 2. PCB Layout Guide

Control Register (Control)

I²C Slave Address : 0100101

Addres s	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0		
	Device ID		VEND	OR_ID	L		CHIP	CHIP_REV			
0x03	Reset Value	0	1	0	0	0	0	0	0		
	Read/Write	R	R	R	R	R	R	R	R		
	Control1	Sel_ SWFreq	EN_ STAT	SI	AT	BOOST	PWR_ Rdy	OTG_ PinP	MIVR		
0x00	Reset Value	0	1	0	0	0	0	0	0		
	Read/Write	R/W	R/W	R	R	R	R	R	R		
	Control2		IEOC[2:0]		Higher_ OCP	TE	IIN_INT	HZ	OPA_ MODE		
0x01	Reset Value	0	1	0	0	0	0	0	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	Control3			VOR	EG[5:0]			OTG_PL	OTG_EN		
0x02	Reset Value	0	1	1	0	0	1	1	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	Control4	RST	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved		
0x04	Reset Value	0	0	0	0	0	0	0	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	Control5	SYSUVP_ HW_SEL	OTG_OC	SYS_N	/lin[1:0]		IPRE	C[3:0]	2[3:0]		
0x05	Reset Value	1	0	0	1	0	0	1	1		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	Control6		ICHRG[3:0] EN_OSCSS			VPREC[2:0]					
0x06	Reset Value	0	0	0	0	0	0	1	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	Control7	CC_JEITA	BATD_EN	Chip_EN	CHG_EN	TS_HOT	TS_ WARM	TS_COOL	TS_COLD		
0x07	Reset Value	0	0	1	1	0	0	0	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	Control8	Reserved	Reserved	Reserved	Reserved	Reserved	PP	SenseNode [2:0]		
0x1C	Reset Value	1	0	0	1	1	1	0	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	IRQ1	TSDI	VINOVPI	WakeUpI	WatchDogl	Reserved	CHTERM_ TMRI	SYSUVP	BATAB		
0x08	Reset Value	0	0	0	0	0	0	0	0		
	Read/Write	R	R	R	R	R	R	R	R		



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	IRQ2	CHRVPI	CHBADI	CHBATOVI	CHTERMI	CHRCHGI	CHTMRI	CHTREGI	SYSWAKE UPI
0x09	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R	R	R	R	R	R	R	R
	IRQ3	BSTVINOVI	BSTOLI	BSTLOWVI	Reserved	Reserved	Reserved	Reserved	Reserved
0x0A	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R	R	R	R	R	R	R	R
	Mask 1	TSDIM	VINOVPIM	WakeUpIM	WatchDog IM	Reserved	CHTERM_ TMRIM	SYSUVP IM	BATABM
0x0B	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Mask 2	CHRVPIM	CHBADIM	CHBATOV IM	CHTERMIM	CHRCHGIM	CHTMRIM	CHTREGI M	SYSWAKE UPIM
0x0C	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Mask 3	BSTVINOV IM	BSTOLIM	BSTLOW VIM	Reserved	Reserved	Reserved	Reserved	Reserved
0x0D	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Control-DP DM	C	CHG_TYP[2:0)]	IINLMT	MTSEL[1:0] CHG_ 2DET		CHG_ 1DET	CHGRUN
0x0E	Reset Value	0	0	0	1	0	1	1	0
	Read/Write	R	R	R	R/W	R/W	R/W	R/W	R
	Control 9	Reserved	PPC_ CTRL_SEL	EN_ PPCTRL	MIVR_ ENB		MIVR_L	VL[3:0]	
0x21	Reset Value	0	1	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Control 10	CLR_DP	DP_STAT		WT_FC[2:0]		WT_PR	RC[1:0]	TMR_ Pause
0x22	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R	R/W	R/W	R/W	R/W	R/W	R/W
	Control 11			AICR[4:0]	<u> </u>				
0x23	Reset Value	0	0	1	0	1	1	1	1
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

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Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	Control 12	EOC_T	imer[1:0]	Wa	WakeUp_Timer[2:0]			IRQ_ Pulse	IRQ_REZ
0x24	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	Control 13	WDT_EN	Reserved	Reserved	TWDTRST	Reserved	Reserved	TWD	T[1:0]
0x25	Reset Value	0	0	0	1	0	0	1	1
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	STAT IRQ	TSHOTI	TSWARMI	TSCOOLI	TSCOLDI	PWR_Rdyl	MIVRI	Reserved	Reserved
0x26	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
	STAT IRQ Mask	TSHOTIM	TSWARMIM	TSCOOLI M	TSCOLDI M	PWR_ RdyIM	MIVRIM	Reserved	Reserved
0x27	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	Control 1	Sel_ SWFreq	EN_ STAT	ST	TAT	BOOST	PWR_ Rdy	OTG_ Pinp	MIVR
0x00	Reset Value	0	1	0	0	0	0	0	0
	Read/Write	R/W	R/W	R	R	R	R	R	R
Sel_S	SWFreq	The switching 0 : The switch 1 : The switch	hing frequen	cy is 1.5M	IHz	er/OTG)			
EN_	STAT	0 : Disable S 1 : Enable S							
S	TAT	Charger statu 00 : Ready 01 : Charge i 10 : Charge o 11 : Fault	n progress						
BC	OST	0 : Not in boo 1 : Boost mo							
PWI	R_Rdy	Power status 0 : Input pow 1 : Input pow	er is bad, VII						
ото	S_PinP	OTG pin pola 0 : OTG inpu 1 : OTG inpu	t pin is low						
Μ	IVR	MIVR status 0 : MIVR reg 1 : MIVR reg	ulation is ina						
	Control 2	I	EOC[2:0]		Higher_ OCP	TE	IIN_INT	HZ	OPA_ MODE
0x01	Reset Value	0	1	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
IE	OC	EOC current 000 : 100mA 001 : 150mA 010 : 200mA 011 : 250mA 100 : 300mA 101 : 350mA 110 : 400mA 111 : 450mA	-						
Highe	er_OCP	Charger/OTC 0 : OCP = 4.9 1 : OCP = 6A	5A	selection					
	TE	Charge curre 0 : Disable ch 1 : Enable ch	narge current	t terminat	on	control			

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Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0		
IIN	_INT	IAICR setting 0 : Decided b limit when O 1 : Decided b	y external C G pin is higl	י ר			•	n is low and	1A current		
ŀ	ΗZ	0 : Not high ir 1 : High impe									
OPA_	_MODE	0 : Charger n 1 : Boost moo									
	Control 3		VOREG[5:0]								
0x02	Reset Value	0									
	Read/Write	R/W	R/W	R/W	R/W						
VOR	EG[5:0]	00 0000 : 3.5 00 0011 : 3.5 00 0010 : 3.5 01 1000 : 3.9 01 1001 : 4.0 01 1010 : 4.0 10 0111 : 4.24 10 1000 : 4.3 10 1001 : 4.3 10 1110 : 4.44 11 0110 : 4.50 11 0111 : 4.60 11 1000 : 4.6 11 1111 : 4.62	2V / 4.45V 4V / 4.475V 8V / 5.025 V 0V / 5.05V 2 / 5.075V 8V / 5.4V 0V / 5.425V 2V / 5.575V 4V / 5.6V 8V / 5.775V 0V / 5.8V 2V / 5.825V								
ОТО	G PL	0 : Active at l									
	_ G_EN	0 : Disable O	Active at High level Disable OTG Pin Enable OTG Pin								



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
	Device ID		VEND	OR_ID			CHIF	P_REV		
0x03	Reset Value	0	1	0	0	0	0	0	0	
	Read/Write	R	R	R	R	R	R	R	R	
VEN	DOR_ID	Vendor Ide	ntification :	Richtek : 0 ²	100b					
CHI	P_REV	Chip Revis	ion							
	Control 4	RST	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	
0x04	Reset Value	0	0	0	0	0 0 0 0				
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
F	RST	Write : 1-Charger in reset mode, 0-No effect, Read : always get "0"								
	Control 5	SYSUVP_ HW_SEL								
0x05	Reset Value	1	0	0	1	0	0	1	1	
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
	P_HW_SEL		ng is not tur ng is turned	ned off whe off when S	t n System U ystem UVP	VP				
SYS_	Min[1:0]	System mir 00 : 3.5V 01 : 3.6V 10 : 3.7V 11 : 3.8V	nimum regu	lation volta	ge					
IPRI	EC[3:0]	0000 : 100r 0001 : 150r 0010 : 200r 0011 : 250r 0100 : 300r 0101 : 350r 0110 : 400r 0111 : 450r 1000 : 500r 1001 : 550r 1010 : 600r 1011 : 650r 1100 : 700r 1101 : 750r 1110 : 800r 1111 : 850r	mA mA mA mA mA mA mA mA mA mA mA mA							





Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	Control 6		ICHR	G[3:0]		EN_OSC SS		VPREC[2:0]	•
0x06	Reset Value	0	0	0	0	0	0	1	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
		Charging 0000 : 1.2 0001 : 1.3 0010 : 1.3	25A 375A	etting (Reco	ommed to	set REG0x ²	1C [2:0] = 111)	
ICHF	RG[3:0]	0110 : 2A 1010 : 2.{							
		 1110 : 3A 1111 : 3.1							
EN_0	OSCSS	Enable si 0 : Disabl 1 : Enable	e spread		ad specti	rum			
VPR	EC[2:0]	000 : 2V 001 : 2.2V 010 : 2.4V 011 : 2.6V 100 : 2.8V 101 : 3.0V	/ / / /	e threshold					
		111 : 3.0			CHC			те	
	Control 7	CC_ JEITA	BATD_ EN	CHIP_EN	CHG_ EN	TS_HOT	TS_WARM	TS_ COOL	TS_COLD
0x07	Reset Value	0	0	1	1	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R	R	R	R
CC [_]	JEITA	Charging 0 : ICHR(1 : ICHR(3	etting bit					
BAT	D_EN	Battery de 0 : Disabl 1 : Enable	e battery		done				
CH	P_EN	Chip enal 0 : Chip is 1 : Chip is	s disabled						
CH	G_EN	Charger e 0 : Charg 1 : Charg	er is disal	oled					
TS_	HOIT	Temperat 0 : Norma 1 : Tempe	al tempera	ature					



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
TS_	WARM	0 : Normal	re status rea temperature ature is war	е					
TS_	COOL	0 : Normal	re status rea temperature ature is coo	e					
TS_	COLD	0 : Normal	re status rea temperature ature is colo	е					
	Control 8	Reserved	d Reserved Reserved Reserved Reserved PPSenseNo					nseNode [2:0]
0x1C	Reset Value	1	0	0	1	1	1	0	0
l	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
PPSense	eNode [2:0]	100 : defau 	ower path current sensing adjustment 0 : default setting 1 : recommended setting						
	IRQ 1	TSDI	VINOVPI	WakeUpI	WatchDogI	Reserved	CHTERM_ TMRI	SYSUV PI	BATABI
0x08	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R	R	R	R	R	R	R	R
т	SDI	Thermal sh threshold	utdown fau	lt. Set if the	die tempera	ture exceed	s the therma	I shutdowr	1
VIN	IOVPI	0 : Normal	oltage prote P is detected						
Wa	keUpl	WakeUp tir 0 : Normal 1 : WakeUp	mer fault o timer is ex	pired					
Wate	chDogl	WatchDog 0 : Normal 1 : WatchD	timer fault og timer is o	expired					
CHTEF	RM_TMRI	EOC timer 0 : Normal 1 : EOC tin	fault ner is expire	ed					
SYS	SUVPI	System UV 0 : Normal 1 : SYSUV	′P fault P is triggere	ed					
BA	TABI	Battery abs 0 : Normal 1 : Battery	sence fault b absence	oit					

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Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	IRQ 2	CHRVPI	CHBADI	CHBATO VI	CHTERM I	CHRCH GI	CHTMRI	CHTREGI	SYSWAK EUPI
0x09	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R	R	R	R	R	R	R	R
CH	IRVPI	Charger fa	ult. Reverse	e protection	(VIN < BAT	S + VSLP)			
CH	IBADI	Charger fa	ult. Bad ada	aptor (Poor	Input source	e or VIN < ∖	/UVLO)		
CHE	BATOVI	Charger fa	ult. Battery	OVP					
CH	TERMI	Charge ter	minated						
CHF	RCHGI Recharge request (VBATS < VOREG – VRECH)								
СН	TMRI	Charger fa	ult. Timer ti	me-out					
CH	TREGI	Charger wa	arning. The	rmal regulat	tion loop act	live			
SYSW	/AKEUPI	Battery vol	tage is high	enough to	wakeup sys	tem			
	IRQ 3	BSTVINO VI	BSTOLI	BSTLOW VI	Reserved	Reserved	Reserved	Reserved	Reserved
0x0A	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R	R	R	R	R	R	R	R
BST	VINOVI	Boost fault	VIN OVP	(VIN > VIN_	BOVP)	•			
BS	TOLI	Boost fault	Over load						
BST	LOWVI	Boost fault	Battery vo	ltage is too	low				
	Mask 1	TSDIM	VINOVP IM	WakeUpI M	WatchDo gIM	Reserved	CHTERM _TMRIM	SYSUVP IM	BATABIM
0x0B	Reset Value	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
т	SDIM	TSDI fault i 0 : Interrup 1 : Interrup	t is not mas	sked					
VIN	OVPIM	VIN OVP fa 0 : Interrup 1 : Interrup	t is not mas	sked					
Wak	сeUpIM	WakeUp tir 0 : Interrup 1 : Interrup	t is not mas	sked					
Watc	hDogIM	WatchDog 0 : Interrup 1 : Interrup	t is not mas	sked					
CHTER	M_TMRIM	EOC timer 0 : Interrup 1 : Interrup	t is not mas	sked					



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0				
SYS	UVPIM	System UV 0 : Interrupt 1 : Interrupt	t is not mas	ked									
BA	ГАВІМ	0 : Interrupt	Battery absence fault interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked										
	Mask 2	CHRVP IM	CHBAD IM	CHBATO VIM	CHTERM IM	CHRCH GIM	CHTMRI M	CHTREG IM	SYSWAK EUPIM				
0x0C	Reset Value	0											
	Read/Write	R											
CHF	RVPIM	0 : Interrupt	harger reverse protection interrupt mask : Interrupt is not masked : Interrupt is masked										
CHE	BADIM	Charger Ba 0 : Interrupt 1 : Interrupt	t is not mas	ked	sk								
СНВ	ATOVIM	Charger ba 0 : Interrupt 1 : Interrupt	t is not mas	ked,	rupt mask								
CHT	ERMIM	Charge terr 0 : Interrupt 1 : Interrupt	t is not mas	ked									
CHR	CHGIM	Charger rec 0 : Interrupt 1 : Interrupt	t is not mas	ked	ot mask								
СНІ	ſMRIM	Charger tim 0 : Interrupt 1 : Interrupt	t is not mas	ked .	ask								
CHT	REGIM	Charger thermal regulation loop active interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked											
SYSW	AKEUPIM	0 : Interrupt	s interrupt is masked ystem wakeup interrupt mask : Interrupt is not masked : Interrupt is masked										

Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
	Mask 3	BSTVINO VIM	BSTOLI M	BSTLOW VIM	Reserved	Reserved	Reserved	Reserved	Reserved	
0x0D	Reset Value	0	0	0	0	0	0	0	0	
	Read/Write	R	R	R	R	R	R	R	R	
BSTV	'INOVIM	Boost VIN 0 : Interrup 1 : Interrup	t is not mas		nask					
BST	FOLIM	0 : Interrup	bost over load interrupt mask Interrupt is not masked Interrupt is masked							
BSTL	OWVIM	0 : Interrup	ost low battery voltage interrupt mask Interrupt is not masked Interrupt is masked							
	Control DPDM	CI	HG_TYP[2:	0]	IINLMTS	SEL[1:0]	CHG_ 2DET	CHG_ 1DET	CHGRUN	
0x0E	Reset Value	0	0	0	1	0	1	1	0	
	Read/Write	R	R	R	R/W	R/W	R/W	R/W	R	
CHG_	TYP[2:0]	001 : Sony 010 : Sony 011 : Apple 100 : Apple 101 : Nikor	lard USB C Charger -1 Charger -2 Charger ((Charger (Charger (Ging Downs	harger (SD 2 0.5A) 1A) 1A) tream Port	P) (CDP) (High	n Current He	ost/Hub)			
IINLM	[SEL[1:0]	01 : IAICR[10 : Input li	TYP[2:0] is [4:0] is appl mit is set to	applied and ied and igno the higher	d ignore IAIC ore CHG_T` level of IAIC evel of IAIC	YP[2:0] CR[4:0] and				
CHG	_2DET	and DCP). 0 : Second	Set this bit ary Charge					on (to distin	guish CDP	
CHG	_1DET	charger typ charger de 0 : Primary	e when VII tection. Charger D							
СН	GRUN	running or	not. ⁻ Detection	is not runni	letector stati	us bit. It me	ans the cha	arger detect	ion is	



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0		
	Control 9	Reserved	PPC_ CTRL_SEL	EN_ PPCTRL	MIVR_ ENB		MIVR_	_LVL[3:0]			
0x21	Reset Value	0	1	0	0	0	0	0	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
PPC_C	TRL_SEL	0 : Controll	PPCTRL control by Software (SW) or Hardware (HW) Controlled by SW Controlled by HW								
EN_F	PCTRL	0: PPCTRL	ower-path cor _ pin Internall _ pin Internall	y pulled hig	h to VSYS	; –	CTRL_SEL	= 0			
MIVI	R_ENB	0 : MIVR re	MIVR regula egulation is er egulation is di	nabled							
MIVR_	_LVL[3:0]	Control the 0000 : 4.0\ 0001 : 4.25 0010 : 4.5\ 0011 : 4.75 0100 : 7.0\ 0101 : 7.5\ 0110 : 8.0\ 0111 : 8.5\	5V / / / /	ition level							

Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
	Control 10	CLR_DP	DP_ STAT		WT_FC[2:0]		WT_P	RC[1:0]	TMR_ Pause	
0x22	Reset Value	0	0	0	0	0	0	0	0	
	Read/Write	R/W	R	R/W	R/W	R/W	R/W	R/W	R/W	
CLI	R_DP	Clear DP p 0 : Don't ca 1 : Release	ire	-						
DP_	_STAT	0 : DP pin i	P pin status indication : DP pin is pulled to 0.6V : DP pin is released							
WT_	FC[2:0]	Fast charge 000 : 4hrs 001 : 6hrs 010 : 8hrs 011 : 10hrs 100 : 12hrs 101 : 14hrs 110 : 16hrs 111 : Timer								
WT_F	PRC[1:0]	00 : 30min 01 : 45min 10 : 60min	charge timer : 30min : 45min							
TMR	_Pause	0 : Timer is	Timer control bit) : Timer is active 1 : Timer is paused							



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
	Control 11		IAI	CR[4:0]				Reserved	
0x23	Reset Value	0	0	1	0	1	1	1	1
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
IAIC	R[4:0]	Average Inpu 0000X : 100r 0001X : 150r 0010X : 500r 00110 : 600m 00111 : 700m 01010 : 1A 01011 : 1.1A 01111 : 1.5A 10100 : 2A 11110 : 3A 11111 : Disab	nA nA nA nA	guiation (AICK) Seu	Ing			

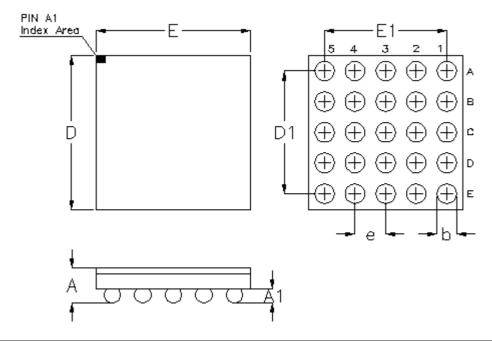
RT9460

Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0		
	Control 12	EOC_Tir	ner[1:0]	Wake	-up Time	er[2:0]	WK_ Timer_EN	IRQ_ Pulse	IRQ_ REZ		
0x24	Reset Value	0	0	0	0	0	0	0	0		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
EOC_1	Fimer[1:0]	The timer of 00 : 0 min 01 : 30 min 10 : 45 min 11 : 60min	back-chargin	g time							
Wake-up	Timer[2:0]	The periodica 000 : 4s 001 : 8s 010 : 16s 011 : 32s 100 : 64s 101 : 2min 110 : 4min 111 : 8min	ally timer IRC) to awake							
WK_T	imer_EN	0 : Timer is d	Control the wake-up timer) : Timer is disabled I : Timer is enabled								
IRQ	_Pulse	Control the IF 0 : The IRQ r 1 : The IRQ r released for 2	eminding is o eminding is o	disabled enabled. If tł	ne IRQ i	s triggered a	and no chec	k action, it v	vill be		
IRC	_REZ	0 : No action	IRQ release control								
	Control 13	WDT_EN	Reserved	Reserved	TWD TRST	Reserved	Reserved	TWD	[1:0]		
0x25	Reset Value	0	0	0	1	0	0	1	1		
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
WD	T_EN	Control watcl 0 : Disable tir 1 : Enable tin	ner and rese	ŧt							
TWI	DTRST	Waiting timer 0 : 200ms 1 : 500ms	to reset I ² C	setup after	watchdo	og is asserte	d				
T : 500ms Watch dog timer, from WDTEN is enabled to watchdog IRQ 00 : 1s TWDT[1:0] 01 : 2s 10 : 4s 11 : 8s											



Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
0x26	STAT IRQ	TSHOTI	TSWARMI	TSCOO LI	TSCOL DI	PWR_ Rdyl	MIVRI	Reserved	Reserved	
	Reset Value	0	0	0	0	0	0	0	0	
	Read/Write	R	R	R	R	R	R	R	R	
TSHOTI		Status IRQ : Interrupt is triggered when TS is entering or exiting HOT region								
TSWARMI		Status IRQ : Interrupt is triggered when TS is entering or exiting WARM region								
TSCOOLI		Status IRQ : Interrupt is triggered when TS is entering or exiting COOL region								
TSCOLDI		Status IRQ : Interrupt is triggered when TS is entering or exiting COLD region								
PWR_Rdyl		Status IRQ : Interrupt is triggered when PWR_Rdy is from bad to good or from good to bad								
MIVRI		Status IRQ : Interrupt is triggered when MIVR loop is from inactive to activate or from active to inactive								
0x27	STAT Mask	TSHOTIM	TSWARM IM	TSCOO LIM	TSCOL DIM	PWR_ RdyIM	MIVRIM	Reserved	Reserved	
	Reset Value	0	0	0	0	0	0	0	0	
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
TSHOTIM		TS in HOT interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked								
TSWARMIM		TS in WARM interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked								
TSCOOLIM		TS in COOL interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked								
TSCOLDIM		TS in COLD interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked								
PWR_RdyIM		PWR_Rdy interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked								
MIVRIM		MIVR interrupt mask 0 : Interrupt is not masked 1 : Interrupt is masked								

Outline Dimension



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	0.525	0.625	0.021	0.025	
A1	0.200	0.260	0.008	0.010	
b	0.290	0.350	0.011	0.014	
D	2.470	2.570	0.097	0.101	
D1	2.000		0.079		
E	2.470	2.570	0.097	0.101	
E1	2.0	000	0.079		
е	0.5	500	0.020		

25B WL-CSP 2.52x2.52 Package (BSC)

Richtek Technology Corporation

14F, No. 8, Tai Yuen 1st Street, Chupei City Hsinchu, Taiwan, R.O.C. Tel: (8863)5526789

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Datasheet Revision History

Version	Date	Description	Item
05	2023/9/28	Modify	General Description on P1 Features on P1 Ordering Information on P2 Electrical Characteristics on P6 Application Information on P12